Fast Recovery Diode
Type SA25MG2698Z0

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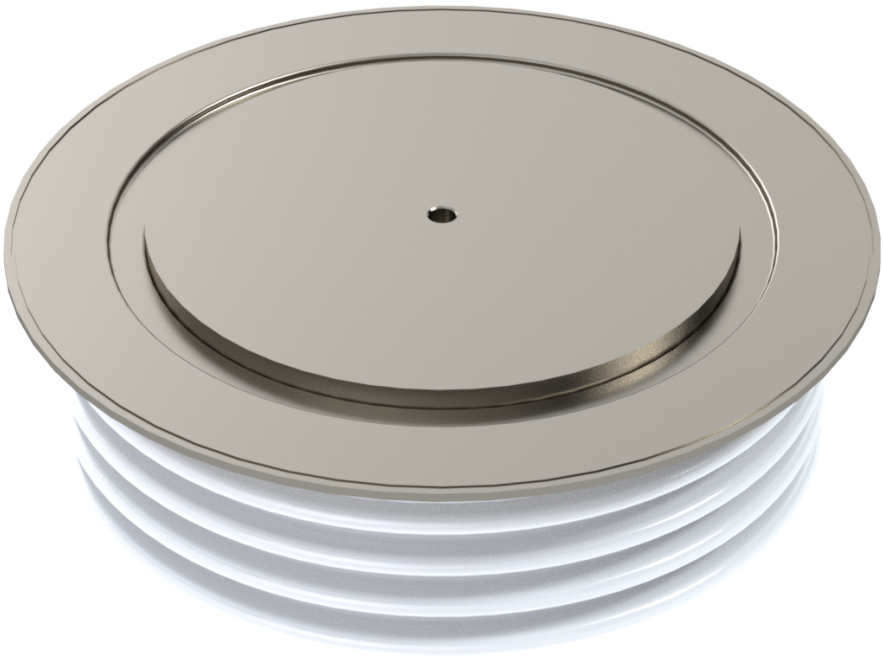
Date: February, 2020
Data Sheet Issue: 1



ORDERING INFORMATION						(Please quote 12 to 15 digit code as below)
SA	25	MG	2698	Z	0	
-	Voltage Code	MP : standard capsule MG : rupture rated capsule ML : extended rupture rated capsule	Current code	Type code	Special code	Optional code

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Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	2500	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	2600	V
V_{RDC}	Maximum reverse D.C. Voltage, (note 1)	1600	V
note 1)	De-Rating factor of 0.13% per °C is applicable for T_j below 25°C		

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T_{sink} = 55°C, (note 1)	2698	A
$I_{F(AV)M}$	Maximum average forward current, T_{sink} = 100°C, (note 1)	1825	A
$I_{F(AV)M}$	Maximum average forward current, T_{sink} = 100°C, (note 2)	1165	A
$I_{F(RMS)}$	Nominal RMS forward current, T_{sink} = 25°C (note 1)	4979	A
$I_{f(d.c.)}$	D.C. forward current, T_{sink} = 25°C (note 3)	4545	A
I_{FSM}	Peak non-repetitive surge current t_p = 10ms, V_{RM} = 60%V_{RRM}, (note 4)	27.8	kA
I_{FSM2}	Peak non-repetitive surge current t_p = 10ms, $V_{RM} \leq$ 10V, (note 4)	30.6	kA
I^2t	I^2t capacity for fusing t_p = 10ms, V_{RM} = 60%V_{RRM}, (note 4)	$3.86 \cdot 10^6$	A^2s
I^2t	I^2t capacity for fusing t_p = 10ms, $V_{RM} \leq$ 10V, (note 4)	$4.68 \cdot 10^6$	A^2s
T_{jop}	Operating temperature range	-40 to +150	°C
T_{stg}	Storage temperature range	-40 to +150	°C
note 1)	Double-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 2)	Single-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 3)	Double-side cooled.		
note 4)	Half-sinewave, 150°C T_j initial.		

Characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
V_{FM}	Maximum peak forward voltage	I_{FM}=6000A	-	-	3.0	V
		I_{FM}=5400A	-	-	2.9	V
V_{T0}	Threshold Voltage		-	-	1.00	V
r_T	Slope resistance		-	-	0.33	mΩ
V_{FRM}	Maximum forward recovery voltage	di/dt = 1000A/µs, T_j = 25°C	-	-	20	V
		di/dt = 1000A/µs	-	-	45	V
I_{RRM}	Peak reverse current	Rated V_{RRM}	-	-	150	mA
Q_{rr}	Recovered charge	I_{FM} = 1000A, t_p = 1000µs, di/dt = 60A/µs, V_R = 50V, 50% Chord.	-	1200	-	µC
Q_{ra}	Recovered charge, 50% Chord		-	620	800	µC
I_{rm}	Reverse recovery current		-	200	-	A
t_{rr}	Reverse recovery time, 50% Chord		-	6.2	-	µs
R_{thJK}	Thermal resistance, junction to heatsink	Double side cooled	-	-	0.011	K/W
		Single side cooled	-	-	0.022	K/W
F	Mounting force	note 2)	37	-	47	kN
W_t	Weight		-	1700	-	g
note 1)	Unless otherwise indicated T_j = 150°C					
note 2)	For other clamp forces consult factory					

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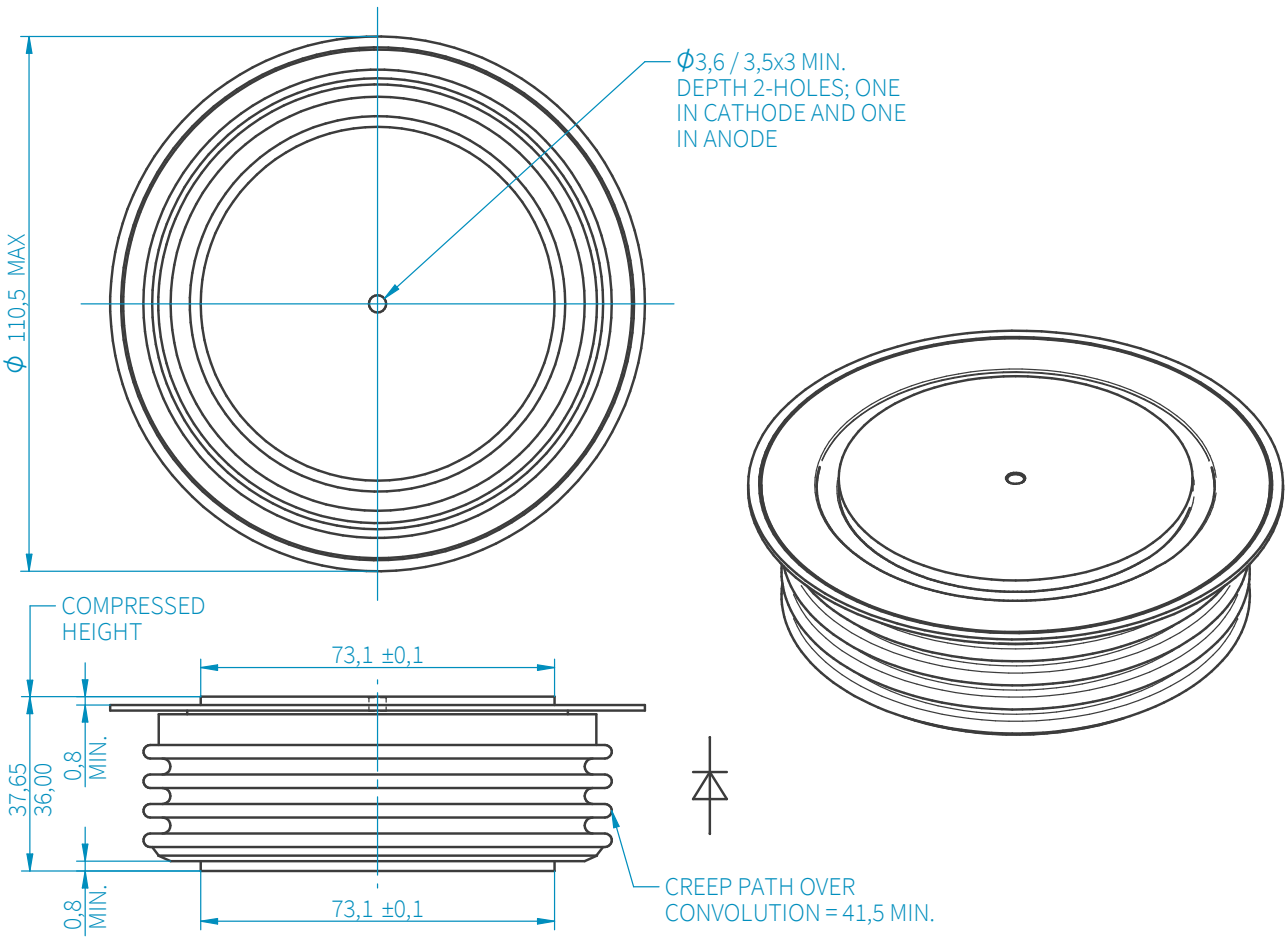
Outline Drawing



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